Vishay Semiconductors

Ultrafast Rectifier, 2 A FRED Pt[®]



www.vishay.com

Cathode O Anode

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 A				
V _R	600 V				
V _F at I _F	0.95 V				
t _{rr}	55 ns				
T _J max.	175 °C				
Package	SMF (DO-219AB)				
Circuit configuration	Single				

FEATURES

- Ultrafast recovery time, reduced Q_{rr}, and soft recovery
- (Pb) RoHS

COMPLIANT HALOGEN

FREE

- 175 °C maximum operating junction temperature
- For PFC CRM, snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Wave and reflow solderable
- Compatible to SOD-123W package case outline
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop, ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, lighting, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SMF (DO-219AB)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V _{RRM}		600	V			
Average rectified forward current	I _{F(AV)}	$T_{\rm C} = 135 \ ^{\circ}{\rm C} \ ^{(1)}$	2	٨			
Non-repetitive peak surge current	I _{FSM}	T_J = 25 °C, 6 ms square pulse	30	A			
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +175	°C			

Note

⁽¹⁾ Device on PCB with 8 mm x 16 mm soldering lands

Revision: 25-May-2021

1

Document Number: 95866



www.vishay.com

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	I _R = 100 μA	600	-	-		
Forward voltage	V	I _F = 2 A	-	1.10	1.35	V	
Forward voltage V _F		I _F = 2 A, T _J = 150 °C	-	0.95	1.15		
Reverse leakage current		V _R = V _R rated	-	-	3		
Reverse leakage current	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	20	100	μA	
Junction capacitance	CT	V _R = 600 V	-	5	-	pF	

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}$	õs, V _R = 30 V	-	42	-	
Reverse recovery time	+	$I_{F} = 0.5 \text{ A}, I_{R} = 1 \text{ A}, I_{rr}$	-	-	55		
neverse recovery time	t _{rr}	T _J = 25 °C		-	40	-	ns
		T _J = 125 °C		-	63	-	
Deels receiver a current	I _{RRM}	T _J = 25 °C	$I_F = 2 A$	-	7.0	-	A
Peak recovery current		T _J = 125 °C	dl _F /dt = 500 A/µs V _R = 400 V	-	8.1	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	140	-	nC
		T _J = 125 °C		-	255	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	+175	°C	
Thermal resistance, junction to mount	R _{thJM} Device mounted on PCB with 8 mm x 16 mm soldering lands		-	-	15	°C/W	
Thermal resistance, junction to ambient	R _{thJA} Device mounted on PCB with 2 mm x 3.5 mm soldering lands		-	-	130	°C/W	
Approximate weight				0.015		g	
Approximate weight				0.0005		oz.	
Marking device		Case style SMF (DO-219AB)	MPU				

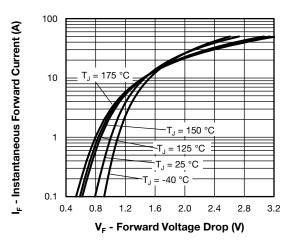


Fig. 1 - Typical Forward Voltage Drop Characteristics

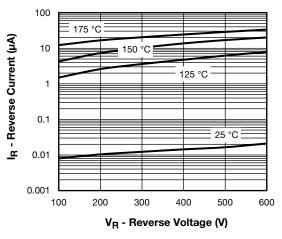


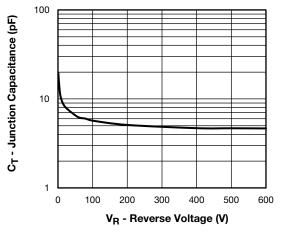
Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

Revision: 25-May-2021

2



Vishay Semiconductors



www.vishay.com

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

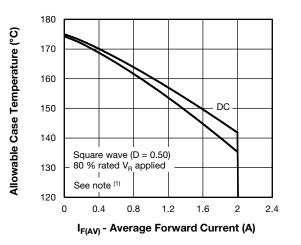


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

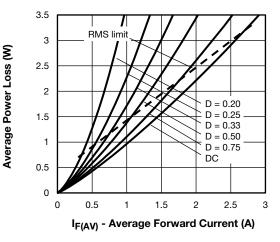


Fig. 5 - Forward Power Loss Characteristics

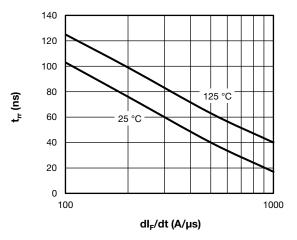


Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt

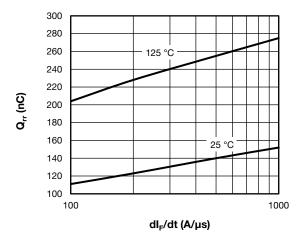


Fig. 7 - Typical Stored Charge vs. dl_F/dt

Note

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ at \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (1 - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ at \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

Revision:	25-Ma	y-2021
-----------	-------	--------

3

Document Number: 95866

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

VS-2EFU06-M3

Vishay Semiconductors

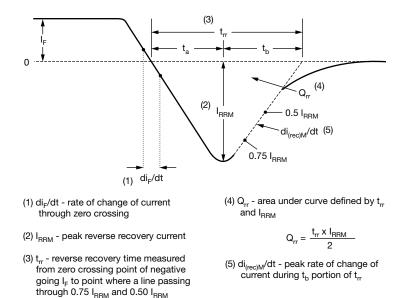


Fig. 8 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

SHAY

www.vishay.com

Device code	VS-	2	E	F	υ	06	-МЗ
		2	3	4	5	6	7
	1	- Cu	hay Sen rrent rat	ing (2 =	2 A)	oduct	
	3	E =	single c	liode	n:		
	4 5	- Pro	: SMF pa ocess typ : ultrafas	be,	arv		
	6		tage co		5		
	7	M	3 = halo	gen-free	e, RoHS	-compli	iant, and

extrapolated to zero current.

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-2EFU06-M3/I	10 000	10 000	13"diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95572				
Part marking information	www.vishay.com/doc?95618				
Packaging information	www.vishay.com/doc?95577				
SPICE model	www.vishay.com/doc?96867				

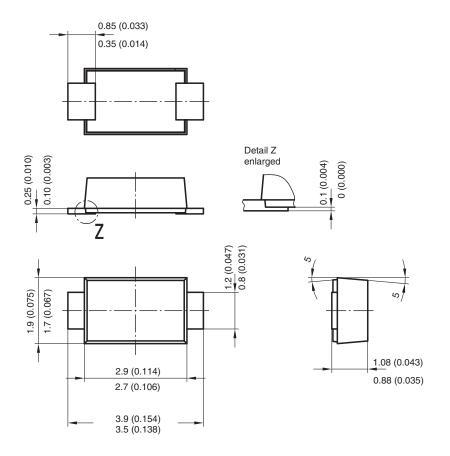
Revision: 25-May-2021



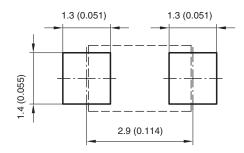
Vishay Semiconductors

SMF (DO-219AB)

DIMENSIONS in millimeters (inches)



Foot print recommendation:



Created - Date: 15. February 2005 Rev. 3 - Date: 13. March 2007 Document no.:S8-V-3915.01-001 (4) 17247



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)